

BTA316X series B, C and E

16 A Three-quadrant triacs high commutation

Rev. 01 — 11 April 2007

Product data sheet

1. Product profile

1.1 General description

Passivated, new generation, high commutation triacs in a SOT186A isolated full pack plastic package

1.2 Features

- Very high commutation performance maximized at each gate sensitivity
- High immunity to dV/dt
- High isolation voltage
- Wide range of gate sensitivities

1.3 Applications

- High power motor control - e.g. washing machines and vacuum cleaners
- Refrigeration and air conditioning compressors
- Non-linear rectifier-fed motor loads
- Electronic thermostats

1.4 Quick reference data

- $V_{DRM} \leq 600$ V (BTA316X-600B/C/E)
- $V_{DRM} \leq 800$ V (BTA316X-800B/C/E)
- $I_{TSM} \leq 140$ A ($t = 20$ ms)
- $I_{T(RMS)} \leq 16$ A
- $I_{GT} \leq 50$ mA (BTA316X series B)
- $I_{GT} \leq 35$ mA (BTA316X series C)
- $I_{GT} \leq 10$ mA (BTA316X series E)

2. Pinning information

Table 1. Pinning

| Pin | Description | Simplified outline | Symbol |
|-----|-------------------------|--------------------------|---------------|
| 1 | main terminal 1 (T1) | <p>SOT186A (TO-220F)</p> | <p>sym051</p> |
| 2 | main terminal 2 (T2) | | |
| 3 | gate (G) | | |
| mb | mounting base; isolated | | |

3. Ordering information

Table 2. Ordering information

| Type number | Package | | Version |
|--------------|---------|---|---------|
| | Name | Description | |
| BTA316X-600B | TO-220F | plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 'full pack' | SOT186A |
| BTA316X-600C | | | |
| BTA316X-600E | | | |
| BTA316X-800B | | | |
| BTA316X-800C | | | |
| BTA316X-800E | | | |

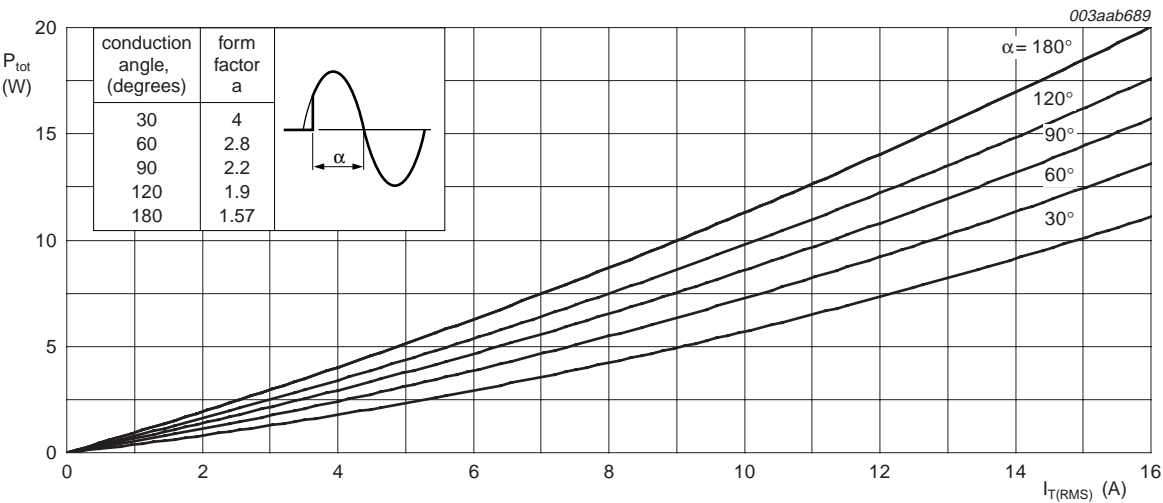
4. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--------------------------------------|---|-------|------|------------------------|
| V_{DRM} | repetitive peak off-state voltage | BTA316X-600B; BTA316X-600C; BTA316X-600E | [1] - | 600 | V |
| | | BTA316X-800B; BTA316X-800C; BTA316X-800E | - | 800 | V |
| $I_{\text{T(RMS)}}$ | RMS on-state current | full sine wave; $T_h \leq 45^\circ\text{C}$; see Figure 4 and 5 | - | 16 | A |
| I_{TSM} | non-repetitive peak on-state current | full sine wave; $T_j = 25^\circ\text{C}$ prior to surge; see Figure 2 and 3 | | | |
| | | $t = 20\text{ ms}$ | - | 140 | A |
| | | $t = 16.7\text{ ms}$ | - | 150 | A |
| I^2t | I^2t for fusing | $t = 10\text{ ms}$ | - | 98 | A^2s |
| di_T/dt | rate of rise of on-state current | $I_{\text{TM}} = 20\text{ A}$; $I_{\text{G}} = 0.2\text{ A}$; $di_{\text{G}}/dt = 0.2\text{ A}/\mu\text{s}$ | - | 100 | $\text{A}/\mu\text{s}$ |
| I_{GM} | peak gate current | | - | 2 | A |
| P_{GM} | peak gate power | | - | 5 | W |
| $P_{\text{G(AV)}}$ | average gate power | over any 20 ms period | - | 0.5 | W |
| T_{stg} | storage temperature | | -40 | +150 | $^\circ\text{C}$ |
| T_j | junction temperature | | - | 125 | $^\circ\text{C}$ |

[1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/ μs .



α = conduction angle

Fig 1. Total power dissipation as a function of RMS on-state current; maximum values

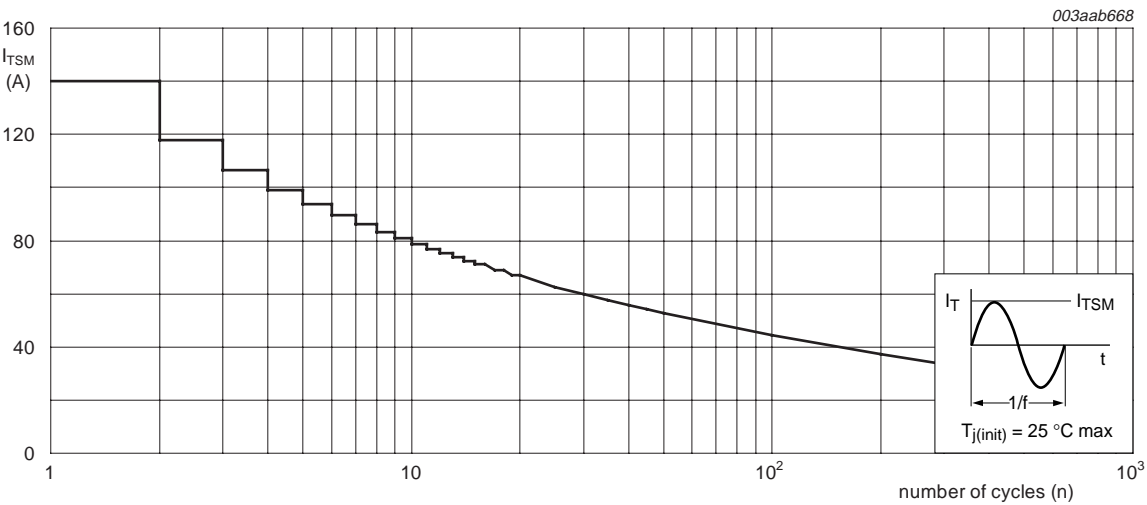
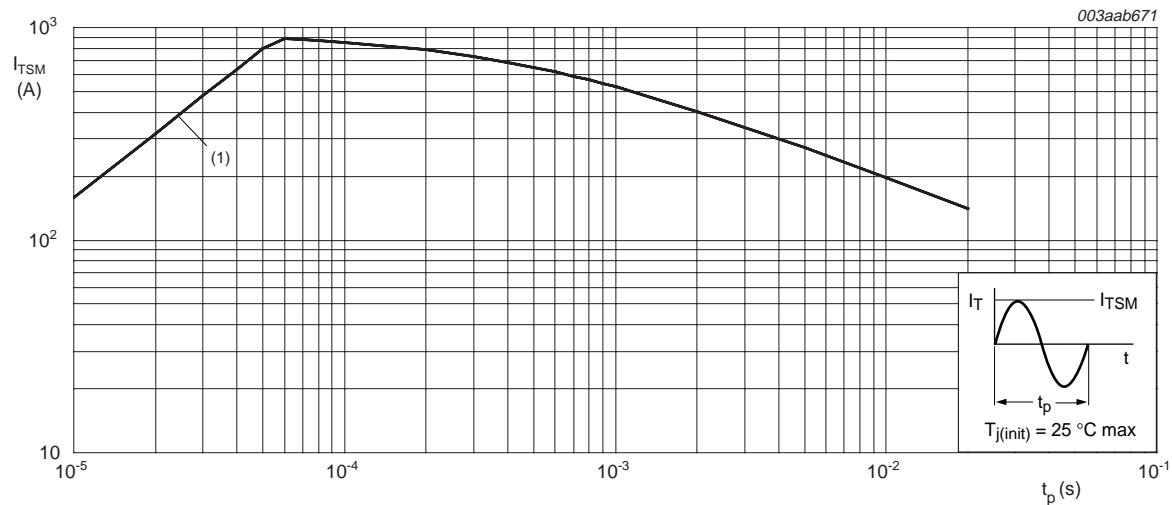
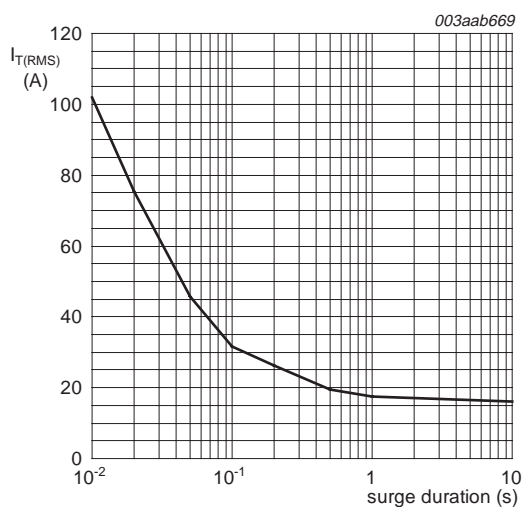


Fig 2. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values



$t_p \leq 20$ ms
(1) di_T/dt limit

Fig 3. Non-repetitive peak on-state current as a function of pulse duration; maximum values



$f = 50$ Hz;
 $T_h = 45^\circ\text{C}$

Fig 4. RMS on-state current as a function of surge duration; maximum values

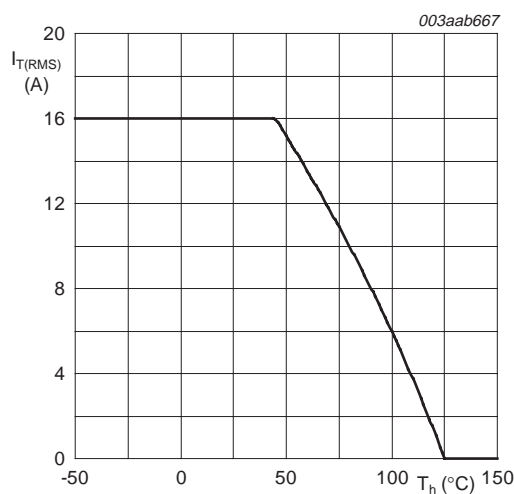
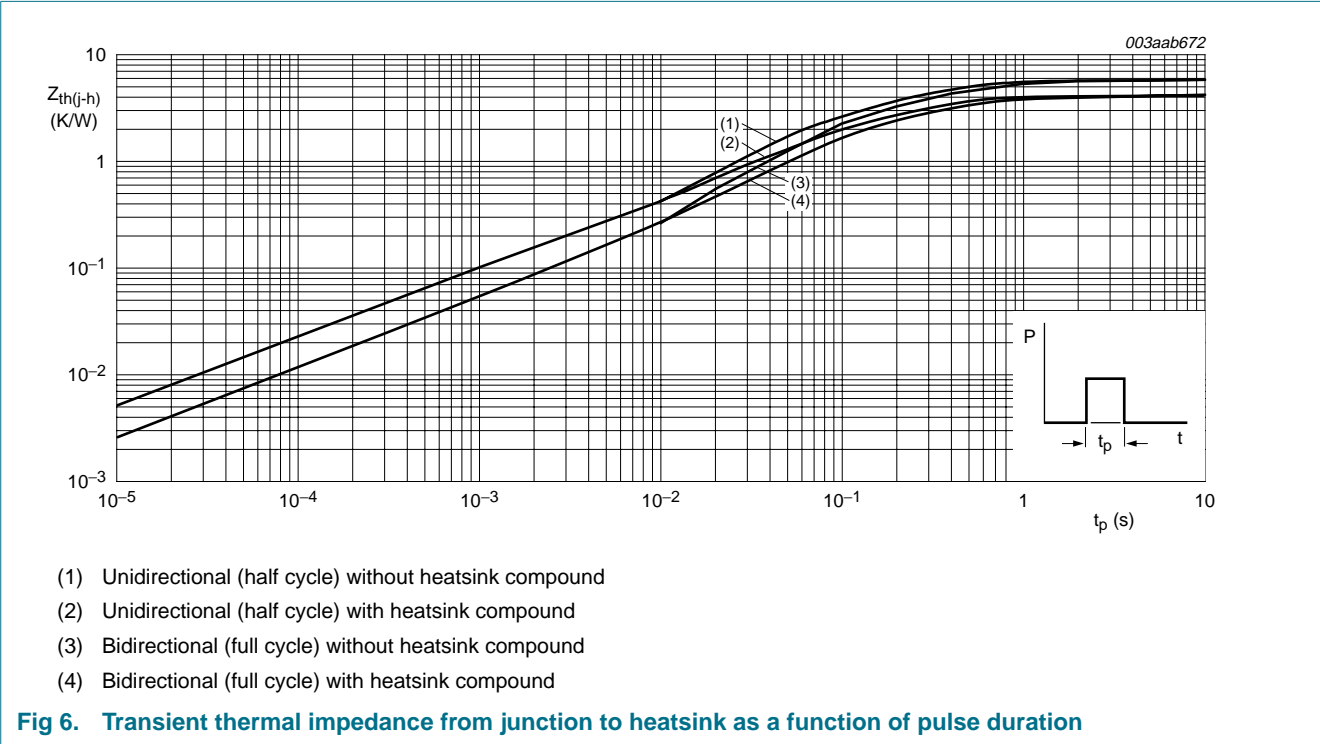


Fig 5. RMS on-state current as a function of heatsink temperature; maximum values

5. Thermal characteristics

Table 4. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------------|--|--|-----|-----|-----|------|
| R _{th(j-h)} | thermal resistance from junction to heatsink | full or half cycle without heatsink compound; see Figure 6 | - | - | 5.5 | K/W |
| | | full or half cycle with heatsink compound; see Figure 6 | - | - | 4.0 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 55 | - | K/W |



6. Isolation characteristics

Table 5. Isolation limiting values and characteristics

$T_h = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------------|-----------------------|--|-----|-----|------|------|
| V _{isol(RMS)} | RMS isolation voltage | from all three terminals to external heatsink; f = 50 Hz to 60 Hz; sinusoidal waveform; RH ≤ 65 %; clean and dust free | - | - | 2500 | V |
| C _{isol} | isolation capacitance | from pin 2 to external heatsink; f = 1 MHz | - | 10 | - | pF |

7. Static characteristics

Table 6. Static characteristics

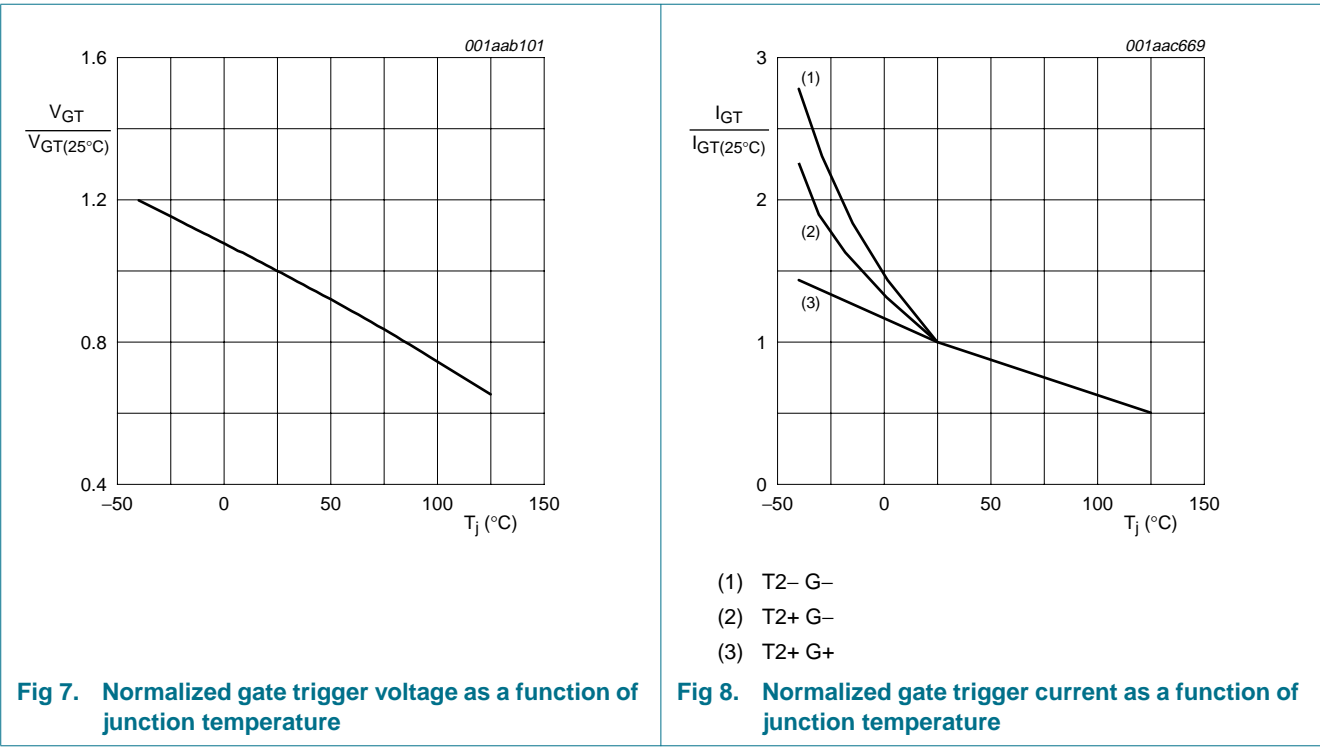
$T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

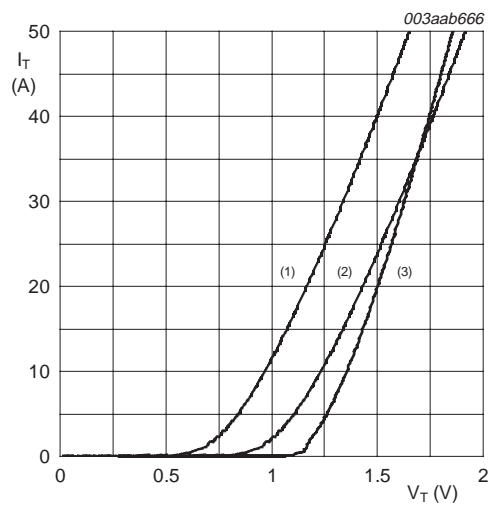
| Symbol | Parameter | Conditions | BTA316X-600B BTA316X-800B | | | BTA316X-600C BTA316X-800C | | | BTA316X-600E BTA316X-800E | | | Unit |
|----------|----------------------|---|------------------------------|-----|-----|------------------------------|-----|-----|------------------------------|-----|-----|------|
| | | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | |
| I_{GT} | gate trigger current | $V_D = 12\text{ V};$ $I_T = 0.1\text{ A};$ see Figure 8 | | | | | | | | | | |
| | | T2+ G+ | 2 | - | 50 | 2 | - | 35 | - | - | 10 | mA |
| | | T2+ G- | 2 | - | 50 | 2 | - | 35 | - | - | 10 | mA |
| | | T2- G- | 2 | - | 50 | 2 | - | 35 | - | - | 10 | mA |
| I_L | latching current | $V_D = 12\text{ V};$ $I_{GT} = 0.1\text{ A};$ see Figure 10 | | | | | | | | | | |
| | | T2+ G+ | - | - | 60 | - | - | 50 | - | - | 25 | mA |
| | | T2+ G- | - | - | 90 | - | - | 60 | - | - | 30 | mA |
| | | T2- G- | - | - | 60 | - | - | 50 | - | - | 30 | mA |
| I_H | holding current | $V_D = 12\text{ V};$ $I_{GT} = 0.1\text{ A};$ see Figure 11 | - | - | 60 | - | - | 35 | - | - | 15 | mA |
| V_T | on-state voltage | $I_T = 18\text{ A};$ see Figure 9 | - | 1.3 | 1.5 | - | 1.3 | 1.5 | - | 1.3 | 1.5 | V |
| V_{GT} | gate trigger voltage | $V_D = 12\text{ V};$ $I_T = 0.1\text{ A};$ see Figure 7 | - | 0.8 | 1.5 | - | 0.8 | 1.5 | - | 0.8 | 1.5 | V |
| | | $V_D = 400\text{ V};$ $I_T = 0.1\text{ A};$ $T_j = 125\text{ }^{\circ}\text{C}$ | 0.25 | 0.4 | - | 0.25 | 0.4 | - | 0.25 | 0.4 | - | V |
| I_D | off-state current | $V_D = V_{DRM(max)};$ $T_j = 125\text{ }^{\circ}\text{C}$ | - | 0.1 | 0.5 | - | 0.1 | 0.5 | - | 0.1 | 0.5 | mA |

8. Dynamic characteristics

Table 7. Dynamic characteristics

| Symbol | Parameter | Conditions | BTA316X-600B BTA316X-800B | | | BTA316X-600C BTA316X-800C | | | BTA316X-600E BTA316X-800E | | | Unit |
|---------------|---------------------------------------|--|------------------------------|-----|-----|------------------------------|-----|-----|------------------------------|-----|-----|------------------|
| | | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | |
| dV_D/dt | rate of rise of off-state voltage | $V_{DM} = 0.67 \times V_{DRM(max)}$; $T_j = 125\text{ }^{\circ}\text{C}$; exponential waveform; gate open circuit | 1000 | - | - | 500 | - | - | 60 | - | - | V/ μs |
| di_{com}/dt | rate of change of commutating current | $V_{DM} = 400\text{ V}$; $T_j = 125\text{ }^{\circ}\text{C}$; $I_{T(RMS)} = 16\text{ A}$; without snubber; gate open circuit | 20 | - | - | 15 | - | - | 5 | - | - | A/ms |
| | | $V_{DM} = 400\text{ V}$; $T_j = 125\text{ }^{\circ}\text{C}$; $I_{T(RMS)} = 16\text{ A}$; $dV/dt = 10\text{ V}/\mu\text{s}$; gate open circuit | - | - | - | - | - | - | 8 | - | - | A/ms |
| | | $V_{DM} = 400\text{ V}$; $T_j = 125\text{ }^{\circ}\text{C}$; $I_{T(RMS)} = 16\text{ A}$; $dV/dt = 1\text{ V}/\mu\text{s}$; gate open circuit | - | - | - | - | - | - | 12 | - | - | A/ms |
| t_{gt} | gate-controlled turn-on time | $I_{TM} = 20\text{ A}$; $V_D = V_{DRM(max)}$; $I_G = 0.1\text{ A}$; $di_G/dt = 5\text{ A}/\mu\text{s}$ | - | 2 | - | - | 2 | - | - | 2 | - | μs |





$V_o = 1.024\text{ V}$
 $R_s = 0.021\text{ }\Omega$
(1) $T_j = 125\text{ }^\circ\text{C}$; typical values
(2) $T_j = 125\text{ }^\circ\text{C}$; maximum values
(3) $T_j = 25\text{ }^\circ\text{C}$; maximum values

Fig 9. On-state current as a function of on-state voltage

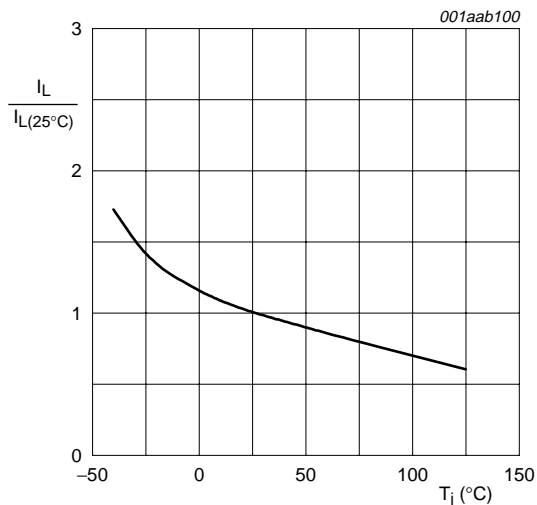


Fig 10. Normalized latching current as a function of junction temperature

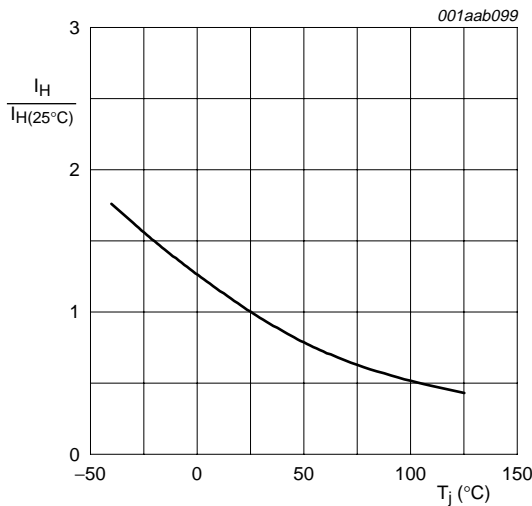


Fig 11. Normalized holding current as a function of junction temperature

9. Package information

Epoxy meets UL94 V-0 at 3.175 mm

10. Package outline

Plastic single-ended package; isolated heatsink mounted;
1 mounting hole; 3-lead TO-220 'full pack'

SOT186A

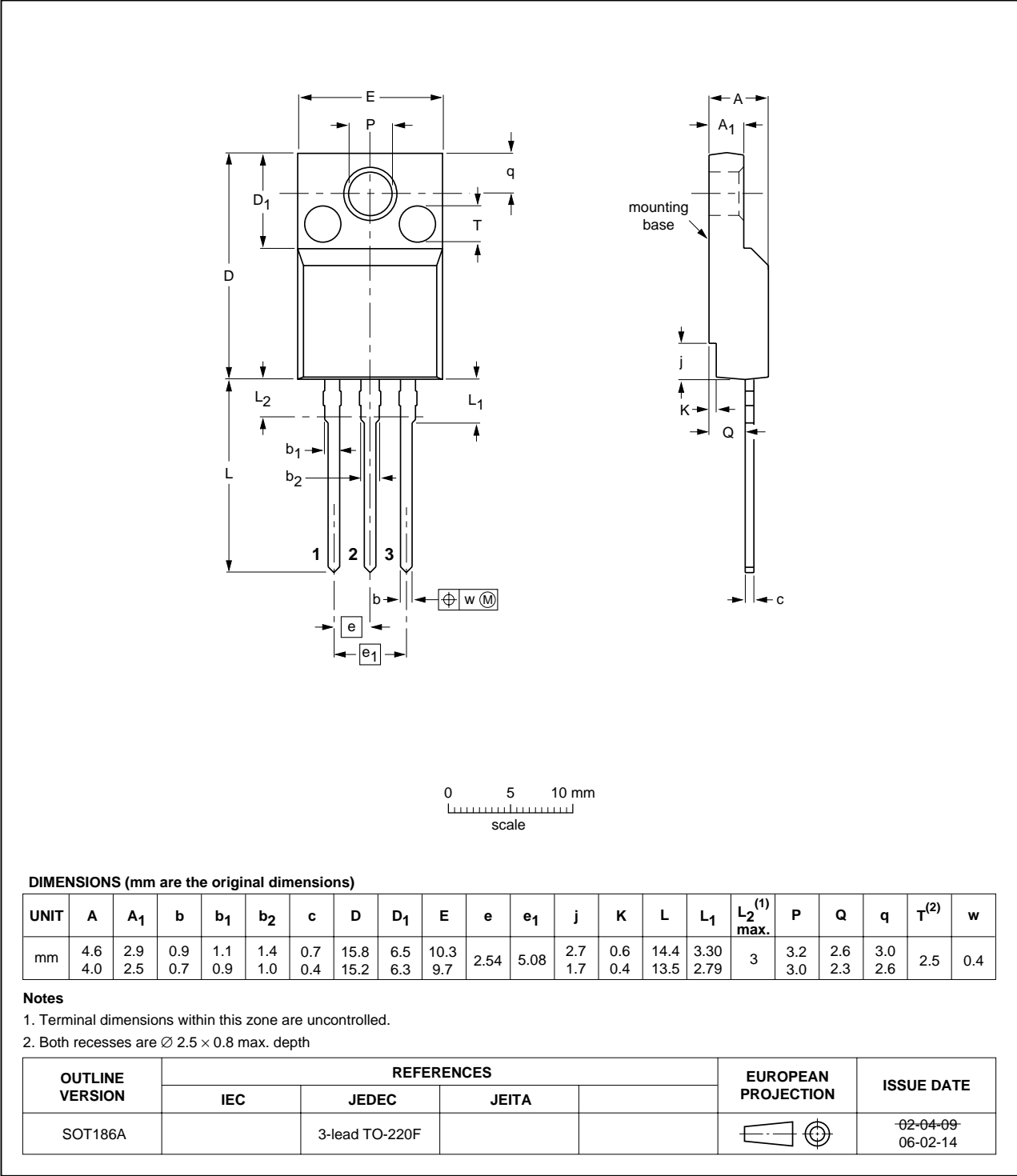


Fig 12. Package outline SOT186A (TO-220F)

11. Revision history

Table 8. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|---------------------|--------------|--------------------|---------------|------------|
| BTA316X_SER_B_C_E_1 | 20070411 | Product data sheet | - | - |

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| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
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